



MBR3100

HIGH VOLTAGE POWER SCHOTTKY RECTIFIER

Product Summary

V _{RRM} (V)	I _O (A)	V _{F (MAX)} (V) @ +25°C	I _{R (MAX)} (mA) @ +25°C
100	3	0.85	0.5

Description

The MBR3100 is a high voltage Schottky rectifier suited for switch mode power supplies and other power converters. This device is intended for use in medium voltage operation, and particularly, in high frequency circuits where low switching losses and low noise are required.

The MBR3100 is available in standard DO-214AC package.

Applications

- Power Supply-Output Rectification
- Power Management
- Instrumentation

Features

- Low Forward Voltage: 0.85V at +25°C
- High Surge Current Capacity
- Operating Junction Temperature: +150°C
- 3A Total
- Guard-Ring for Stress Protection
- Available in "Green" Package: DO-214AC
 - Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
 - Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: DO-214AC
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (§3)
- Weight (Approximately): 1.9Grams

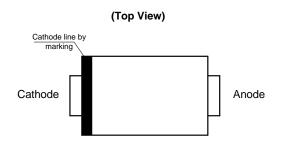


DO-214AC

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

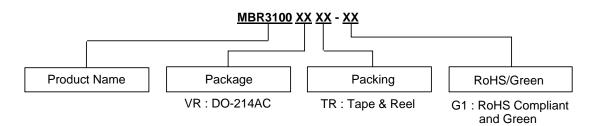
Pin Assignments



DO-214AC



Ordering Information



Package	Part Number	Marking ID	Packing
DO-214AC	MBR3100VRTR-G1	3100VR	7500 Pieces/Tape & Reel

Marking Information

(1) DO-214AC

(Top View)



First Line: Logo and Date Code Y: Year WW: Work Week of Molding A: Assembly House Code Second Line: Marking ID (See Ordering Information)



Maximum Ratings (Note 4)

Characteristic	Symbol	Rating	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _R wm V _R	100	V
Average Rectified Forward Current (Rated V _R , T _C = +141°C)	I _{F(AV)}	3	А
Non Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Half Wave, Single Phase, 60Hz)	I _{FSM}	80	А
Operating Junction Temperature Range (Note 5)	TJ	-65 to +150	°C
Storage Temperature Range	T _{STG}	-65 to +150	°C
Voltage Rate of Change (Rated V _R)	dv/dt	10000	V/µs
ESD (Machine Model = C)	_	400	V
ESD (Human Body Model = 3B)	_	8000	V

Notes:

- 4. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.
- 5. The heat generated must be less than the thermal conductivity from Junction to Ambient: $dP_D/dT_J < 1/\theta_{JA}$.

Thermal Characteristics

Characteristic	Symbol	Rating		Unit
Thermal Resistance (Junction to Lead) (Note 6)	$R_{ heta JL}$	DO-214AC	20	2011
Thermal Resistance (Junction to Ambient) (Note 6)	$R_{ heta JA}$	DO-214AC	70	°C/W

Note 6: Device mounted on heat sink, with minimum recommended pad layout per http://www.diodes.com/package-outlines.html.

Electrical Characteristics

Characteristic	Symbol	Rating	Unit	Test Condition
	V _{F (MAX)}	0.85	V	I _F = 3A, T _C = +25°C
Maximum Instantaneous Forward Voltage Drop (Note 7)		0.7		I _F = 3A, T _C = +125°C
	I _{R (MAX)}	0.5	mA	Rated DC Voltage, T _C = +25°C
Maximum Instantaneous Reverse Current (Note 7)		2.0		Rated DC Voltage, T _C = +125°C

Note 7: Short duration pulse test used to minimize self-heating effect, Pulse Test: Pulse Width = 300μ s, Duty Cycle $\leq 2.0\%$.



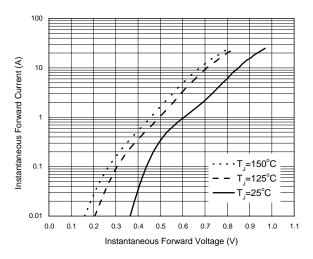


Figure 1. Typical Forward Characteristics

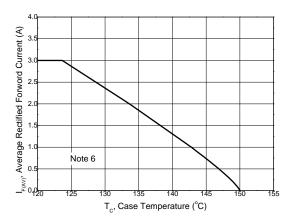


Figure 3. Average Rectified Forward Current vs.

Case Temperature

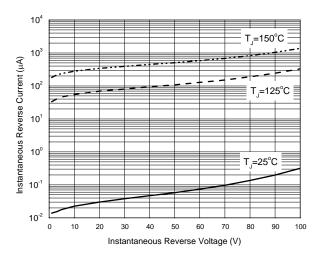


Figure 2. Typical Reverse Characteristics

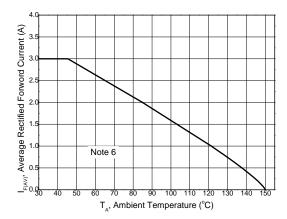


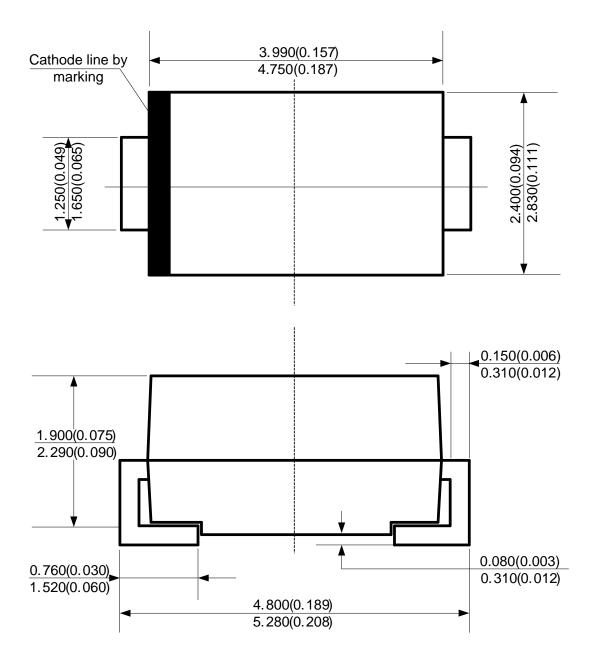
Figure 4. Average Rectified Forward Current vs.

Ambient Temperature



Package Outline Dimensions (All dimensions in mm(inch).)

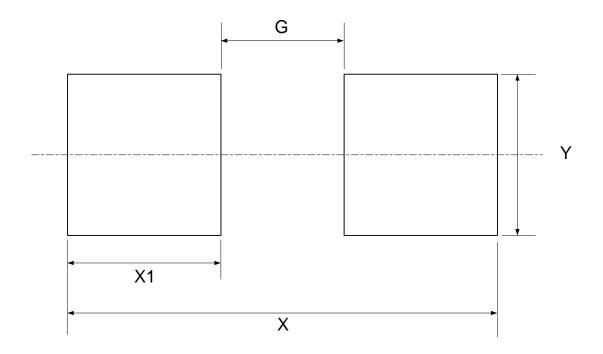
(1) Package Type: DO-214AC





Suggested Pad Layout

(1) Package Type: DO-214AC



Dimensions	Y	X1	G	X
	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)
Value	2.100/0.083	2.000/0.079	1.600/0.063	5.600/0.220



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